



# **MMDTA42**

# DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

## Features

Epitaxial Planar Die Construction

Ideal for Medium Power Amplification and Switching Lead Free/RoHS Compliant (Note 3)

"Green" Device, Note 4 and 5

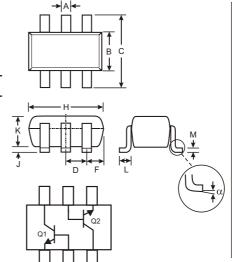
## **Mechanical Data**

Case: SOT-26

Case Material: Molded Plastic, "Green" Molding Compound, Note 5. UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020C Terminal Connections: See Diagram Terminals: Finish - Matte Tin Solderable per MIL-STD-202, Method 208 Lead Free Plating (Matte Tin Finish annealed over Copper leadframe). Marking (See Page 2): K3M

Ordering & Date Code Information: See Page 2

Weight: 0.008 grams (approximate)



SOT-26									
Dim	Min	Мах	Тур						
Α	0.35	0.50	0.38						
В	1.50	1.70	1.60						
С	2.70	3.00	2.80						
D			0.95						
F			0.55						
Н	2.90	3.10	3.00						
J	0.013	0.10	0.05						
К	1.00	1.30	1.10						
L	0.35	0.55	0.40						
Μ	0.10	0.20	0.15						
	0	8							
All Dimensions in mm									

#### Maximum Ratings @ T<sub>A</sub> = 25 C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V <sub>CBO</sub>	300	V	
Collector-Emitter Voltage	V <sub>CEO</sub>	300	V	
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V	
Collector Current (Note 1) (Note 2)	Ι <sub>C</sub>	500	mA	
Power Dissipation (Note 1)	Pd	300	mW	
Thermal Resistance, Junction to Ambient (Note 1)	R <sub>JA</sub>	417	C/W	
Operating and Storage and Temperature Range	Tj, T <sub>STG</sub>	-55 to +150	С	

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

2. When operated under collector-emitter saturation conditions within the safe operating area defined by the thermal resistance rating (R JA), power dissipation rating (Pd) and power derating curve (figure 1).

3. No purposefully added lead.

4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com./products/lead\_free/index.php.

 Product manufactured with Date Code 0609 (week 9, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0609 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



<b>Electrical Characteristics</b>	@ T <sub>A</sub> = 25 C unless otherwise specified
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Characteristic	Symbol	Min	Max	Unit	Test Condition					
OFF CHARACTERISTICS (Note 6)										
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	300		V	$I_{\rm C} = 100$ A, $I_{\rm E} = 0$					
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	300		V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$					
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6.0		V	$I_{\rm E} = 100$ A, $I_{\rm C} = 0$					
Collector Cutoff Current	I <sub>CBO</sub>		100	nA	$V_{CB} = 200V, I_E = 0$					
Collector Cutoff Current	I <sub>EBO</sub>		100	nA	$V_{CE} = 6.0V, I_C = 0$					
ON CHARACTERISTICS (Note 6)										
DC Current Gain	h <sub>FE</sub>	25 40 40								
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>		0.5	V	$I_{C} = 20 \text{mA}, I_{B} = 2.0 \text{mA}$					
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>		0.9	V	$I_{C} = 20mA, I_{B} = 2.0mA$					
SMALL SIGNAL CHARACTERISTICS					•					
Output Capacitance	C <sub>cb</sub>		3.0	pF	$V_{CB} = 20V, f = 1.0MHz, I_E = 0$					
Current Gain-Bandwidth Product	f <sub>T</sub>	50		MHz	$V_{CE} = 20V, I_C = 10mA,$ f = 100MHz					

Notes: 6. Short duration test pulse used to minimize self-heating effect.

# Ordering Information (Note 5 & 7)

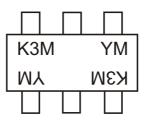
Device	Packaging	Shipping		
MMDTA42-7-F	SOT-26	3000/Tape & Reel		

Notes: 5. Product manufactured with Date Code 0609 (week 9, 2006) and newer are built with Green Molding Compound. Product

manufactured prior to Date Code 0609 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

7. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**

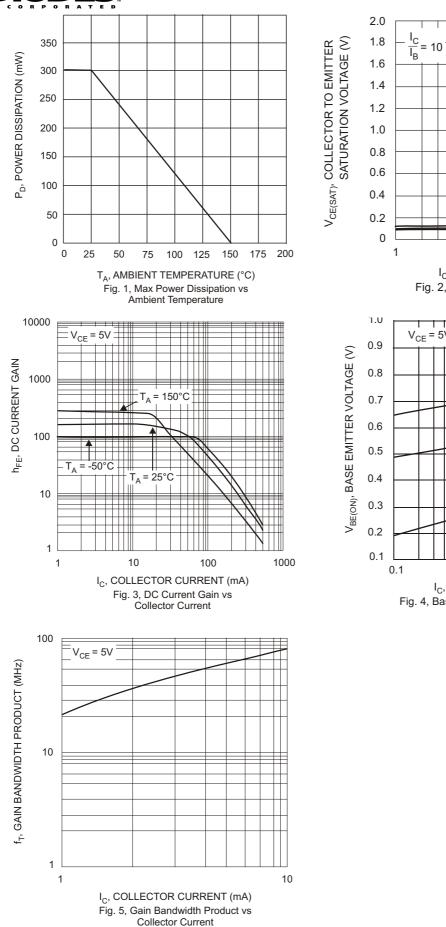


 $\begin{array}{l} \mathsf{K3M} = \mathsf{Product Type Marking Code} \\ \mathsf{YM} = \mathsf{Date Code Marking} \\ \mathsf{Y} = \mathsf{Year ex: P} = 2003 \\ \mathsf{M} = \mathsf{Month ex: 9} = \mathsf{September} \end{array}$ 

Date Code Key

Year	2004		2005	2006	200	07	2008	200	)9	2010	2011	2	2012
Code	R		S	Т	U		V	W	1	Х	Y		Z
Мо	nth	Jar	n Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Co	de	1	2	3	4	5	6	7	8	9	0	Ν	D





T<sub>A</sub> = 25°C = -50°C Τ<sub>A</sub> 10 1000 100 I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 2, Collector Emitter Saturation Voltage vs. Collector Current  $V_{CE} = 5V$ ٦ -50  $\mathsf{T}_\mathsf{A}$ = 25°C ТΙ  $\mathsf{T}_\mathsf{A}$ = 111 10 100 1 I<sub>C</sub>, COLLECTOR CURRENT (mA) Fig. 4, Base Emitter Voltage vs Collector Current

= 150°C

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